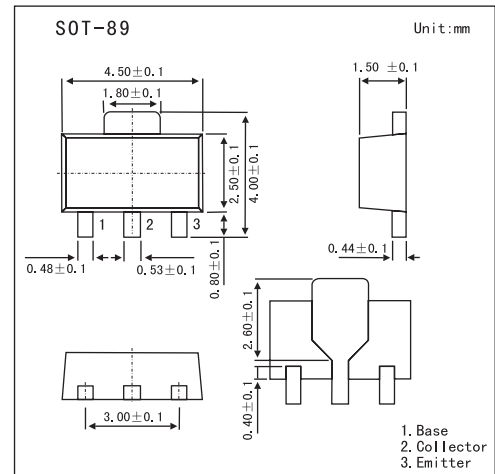


## 2SB766, 2SB766A

### ■ Features

- Large collector power dissipation PC
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing



### ■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit	
Collector-base voltage	2SB766 2SB766A	V <sub>CBO</sub>	-30	V
			-60	
Collector-emitter voltage	2SB766 2SB766A	V <sub>CEO</sub>	-25	V
			-50	
Emitter-base voltage	V <sub>EBO</sub>	-5	V	
Collector current	I <sub>C</sub>	-1	A	
Peak collector current	I <sub>CP</sub>	-1.5	A	
Collector power dissipation	P <sub>C</sub>	-1	W	
Junction temperature	T <sub>j</sub>	150	°C	
Storage temperature	T <sub>stg</sub>	-55 to +150	°C	

## 2SB766, 2SB766A

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditions	Min	Typ	Max	Unit
Collector-base voltage	2SB766	Ic = -10 μA, IE = 0	-30			V
	2SB766A		-60			
Collector-emitter voltage	2SB766	Ic = -2 mA, IB = 0	-25			V
	2SB766A		-50			
Emitter-base voltage	VEBO	IE = -10μA, Ic = 0	-5			V
Collector-base cutoff current	ICBO	V <sub>CB</sub> = -20 V, IE = 0			-0.1	nA
Forward current transfer ratio	hFE	V <sub>CE</sub> = -10 V, Ic = -500 mA	85		340	
		V <sub>CE</sub> = -5 V, Ic = -1 A	50			
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	Ic = -500 mA, IB = -50 mA		-0.2	-0.4	V
Base-emitter saturation voltage	V <sub>BE(sat)</sub>	Ic = -500 mA, IB = -50 mA		-0.85	-1.2	V
Transition frequency	f <sub>T</sub>	V <sub>CB</sub> = -10 V, IE = 50 mA, f = 200 MHz		200		MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = -10 V, IE = 0, f = 1 MHz		20	30	pF

■ hFE Classification

Marking	2SB766(A)/2SB766A(B)		
Rank	Q	R	S
hFE	85~170	120~240	17~340